NSN 5961-01-150-1669

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View Online at https://aerobasegroup.com/nsn/5961-01-150-1669 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 50.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 140.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter and 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig:

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